

PUMD30

50 V, 100 mA NPN/PNP resistor-equipped double transistor; R1 = 2.2 k Ω , R2 = open

31 March 2023

Product data sheet

1. General description

NPN/PNP double Resistor-Equipped Transistor (RET) in a very small SOT363 (SC-88) Surface-Mounted Device (SMD) plastic package.

NPN/NPN complement: PUMH30 PNP/PNP complement: PUMB30

2. Features and benefits

- 100 mA output current capability
- Built-in bias resistors
- · Simplified circuit design
- · Reduces component count
- Reduces pick and place costs
- AEC-Q101 qualified

3. Applications

- Low current peripheral driver
- Cost-saving alternative for BC847BPN
- · Controlling IC inputs
- Switching loads

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per transistor							
V _{CEO}	collector-emitter voltage	open base	[1]	-	-	50	V
Io	output current		[1]	-	-	100	mA
R1	bias resistor 1 (input)		[2]	1.54	2.2	2.86	kΩ

- [1] For the PNP transistor with negative polarity.
- [2] See section "Test information" for resistor calculation and test conditions.



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5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	GND1	GND (emitter) TR1		O1 I2 GND2
2	I1	input (base) TR1	□6 □5 □4	
3	O2	output (collector) TR2		R1 R
4	GND2	GND (emitter) TR2		TR1
5	12	input (base) TR2	H ₁ H ₂ H ₃	R1
6	O1	output (collector) TR1	TSSOP6 (SOT363)	GND1 I1 O2 006aaa269

6. Ordering information

Table 3. Ordering information

Type number	Package				
	Name	Description	Version		
PUMD30		plastic, surface-mounted package; 6 leads; 0.65 mm pitch; 2.1 mm x 1.25 mm x 0.95 mm body	<u>SOT363</u>		

7. Marking

Table 4. Marking codes

Type number	Marking code[1]
PUMD30	%B3

[1] % = placeholder for manufacturing site code

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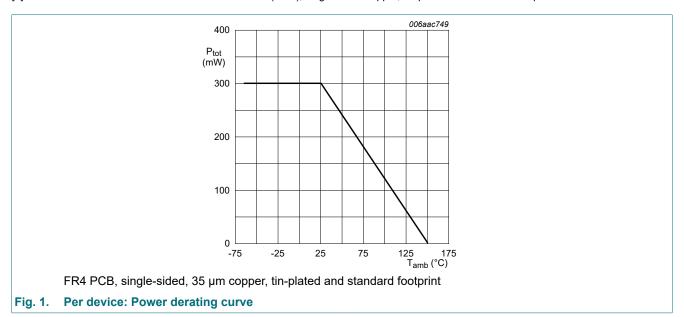
8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
Per transistor						<u>'</u>
V _{CBO}	collector-base voltage	open emitter	[1]	-	50	V
V _{CEO}	collector-emitter voltage	open base	[1]	-	50	V
V _{EBO}	emitter-base voltage	open collector	[1]	-	5	V
Io	output current		[1]	-	100	mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[2]	-	200	mW
Per device						'
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[2]	-	300	mW
Tj	junction temperature			-	150	°C
T _{amb}	ambient temperature			-65	150	°C
T _{stg}	storage temperature			-65	150	°C

- [1] For the PNP transistor with negative polarity.
- [2] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.



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9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per transistor							
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	-	625	K/W
Per device							
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	-	416	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

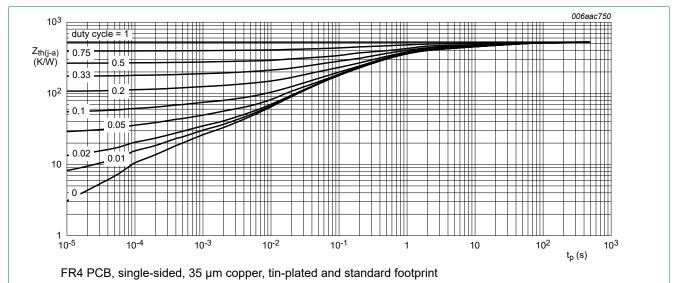


Fig. 2. Per transistor: Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

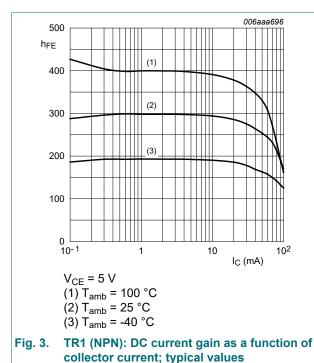
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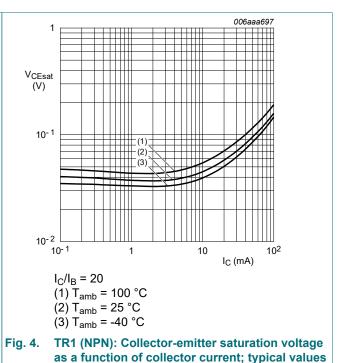
10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per transist	or						
V _{(BR)CBO}	collector-base breakdown voltage	I _C = 100 μA; I _E = 0 A; T _{amb} = 25 °C	[1]	50	-	-	V
$V_{(BR)CEO}$	collector-emitter breakdown voltage	$I_C = 2 \text{ mA}; I_B = 0 \text{ A}; T_{amb} = 25 \text{ °C}$	[1]	50	-	-	V
I _{CBO}	collector-base cut-off current	$V_{CB} = 50 \text{ V}; I_{E} = 0 \text{ A}; T_{amb} = 25 \text{ °C}$	[1]	-	-	100	nA
I _{CEO} collector-emitter cut-off current	collector-emitter cut-off	V _{CE} = 30 V; I _B = 0 A; T _{amb} = 25 °C	[1]	-	-	100	nA
	V _{CE} = 30 V; I _B = 0 A; T _j = 150 °C	[1]	-	-	5	μΑ	
I _{EBO}	emitter-base cut-off current	V _{EB} = 5 V; I _C = 0 A; T _{amb} = 25 °C	[1]	-	-	100	nA
h _{FE}	DC current gain	V _{CE} = 5 V; I _C = 20 mA; T _{amb} = 25 °C	[1]	30	-	-	
V _{CEsat}	collector-emitter saturation voltage	$I_C = 10 \text{ mA}; I_B = 0.5 \text{ mA}; T_{amb} = 25 ^{\circ}C$	[1]	-	-	150	mV
R1	bias resistor 1 (input)		[2]	1.54	2.2	2.86	kΩ
TR1 (NPN)	'						
C _c	collector capacitance	V_{CB} = 10 V; I_{E} = 0 A; i_{e} = 0 A; f = 1 MHz; T_{amb} = 25 °C		-	-	2.5	pF
TR2 (PNP)				'			
C _c	collector capacitance	V _{CB} = -10 V; I _E = 0 A; i _e = 0 A; f = 1 MHz; T _{amb} = 25 °C		-	-	3	pF
		1			_		

- [1] For the PNP transistor with negative polarity.
- [2] See section "Test information" for resistor calculation and test conditions.





50 V, 100 mA NPN/PNP resistor-equipped double transistor; R1 = 2.2 k Ω , R2 = open

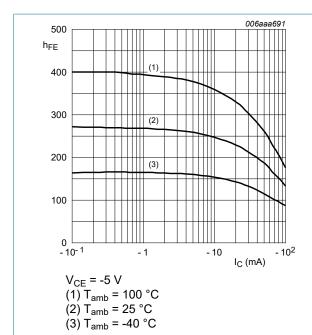


Fig. 5. TR2 (PNP): DC current gain as a function of collector current; typical values

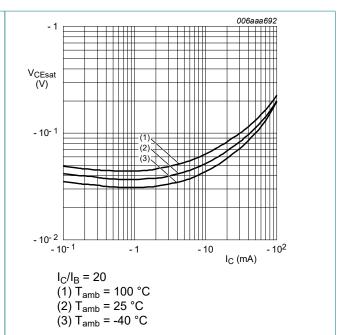


Fig. 6. TR2 (PNP): Collector-emitter saturation voltage as a function of collector current; typical values

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11. Test information

Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101* - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

Resistor calculation

Calculation of bias resistor 1 (R1)

$$R_{I} = \frac{V(I_{2}) - V(I_{I})}{I_{2} - I_{I}}$$

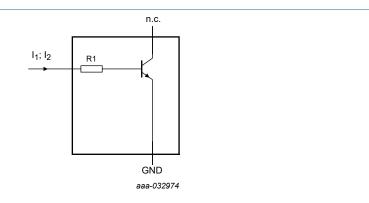


Fig. 7. TR1 (NPN): Resistor test circuit

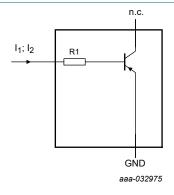


Fig. 8. TR2 (PNP): Resistor test circuit

Resistor test conditions

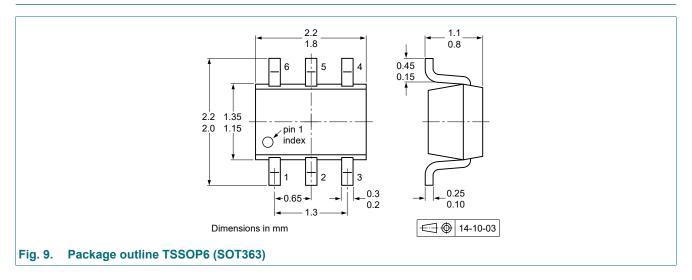
Table 8. Resistor test conditions

PUMD30	R1 (kΩ)	R2 (kΩ)	Test conditions	
			I ₁	l ₂
TR1 (NPN)	2.2	open	750 μΑ	950 μΑ
TR2 (PNP)	2.2	open	-750 μΑ	-950 μΑ

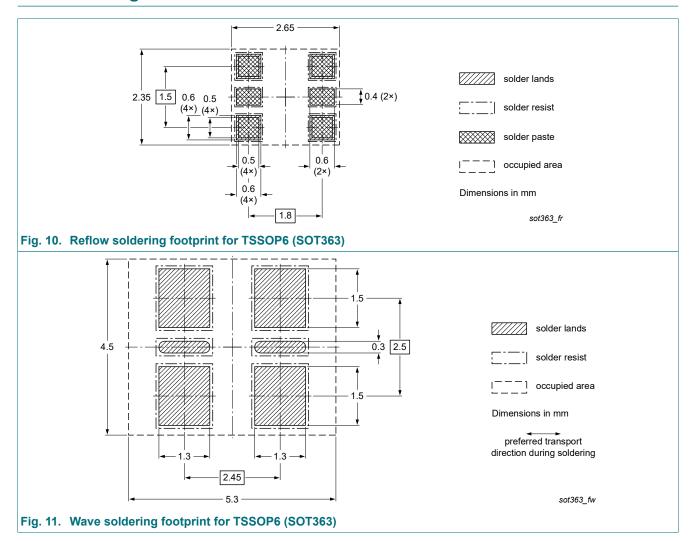
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12. Package outline



13. Soldering



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14. Revision history

Table 9. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
PUMD30 v.2	20230331	Product data sheet	-	PEMD30_PUMD30 v.1
Modifications:	Nexperia. • Legal texts have bee	ta sheet has been redesi en adapted to the new conduced to single type data removed.	mpany name where appro	, ,
PEMD30_PUMD30 v.1	20060331	Product data sheet	-	-

50 V, 100 mA NPN/PNP resistor-equipped double transistor; R1 = 2.2 k Ω , R2 = open

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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